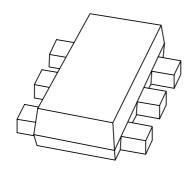
DISCRETE SEMICONDUCTORS

DATA SHEET



PEMH1

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

Preliminary specification

2001 Oct 22





NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1

FEATURES

- 300 mW total power dissipation
- Very small 1.6 × 1.2 mm ultra thin package
- Self alignment during soldering due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- Reduces required PCB area
- Reduced pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

DESCRIPTION

NPN resistor-equipped transistors in a SOT666 plastic package.

MARKING

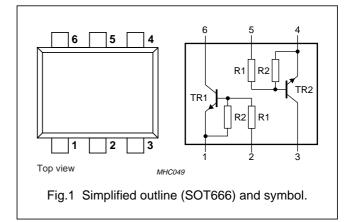
TYPE NUMBER	MARKING CODE
PEMH1	H2

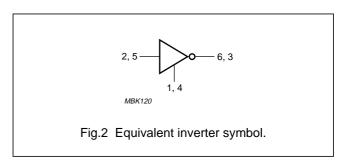
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{CEO}	collector-emitter voltage	50	V
I _{CM}	peak collector current	100	mA
TR1	NPN	_	_
TR2	NPN	_	_
R1	bias resistor	22	kΩ
R2	bias resistor	22	kΩ

PINNING

PIN	DESCRIPTION		
1, 4	emitter	TR1; TR2	
2, 5	base	TR1; TR2	
6, 3	collector	TR1; TR2	





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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per transis	Per transistor						
V _{CBO}	collector-base voltage	open emitter	_	50	V		
V _{CEO}	collector-emitter voltage	open base	_	50	V		
V _{EBO}	emitter-base voltage	open collector	_	10	V		
Vi	input voltage						
	positive		_	+40	V		
	negative		_	-10	V		
Io	output current (DC)		_	100	mA		
I _{CM}	peak collector current		_	100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW		
T _{stg}	storage temperature		-65	+150	°C		
Tj	junction temperature		_	150	°C		
T _{amb}	operating ambient temperature		-65	+150	°C		
Per device	•						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW		

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering method is reflow soldering.

^{1.} Transistor mounted on an FR4 printed-circuit board.

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PEMH1

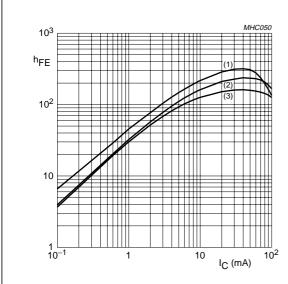
CHARACTERISTICS

 T_{amb} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Per transis	Per transistor						
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0	_	_	100	nA	
I _{CEO}	collector-emitter cut-off current	V _{CE} = 50 V; I _B = 0	_	_	1	μΑ	
		$V_{CE} = 30 \text{ V}; I_{B} = 0; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ	
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0$	_	_	180	μΑ	
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	_	_		
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	_	_	150	mV	
V _{i(off)}	input off voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	_	1.1	0.8	V	
V _{i(on)}	input on voltage	V _{CE} = 0.3 V; I _C = 5 mA	2.5	1.7	_	V	
R1	input resistor		15.4	22	28.6	kΩ	
R2	resistor ratio		0.8	1	1.2		
R2 R1							
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$	_	-	2.5	pF	

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

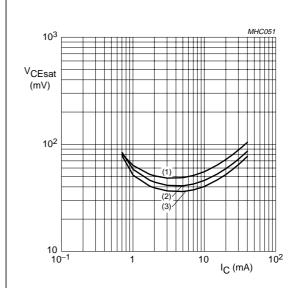
PEMH1



 $V_{CE} = 5 V.$

- (1) T_{amb} = 150 °C.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

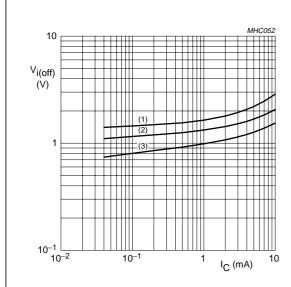
Fig.3 DC current gain as a function of collector current; typical values.



 $I_{\rm C}/I_{\rm B}=20.$

- (1) T_{amb} = 100 °C.
- (2) $T_{amb} = 25 \,^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

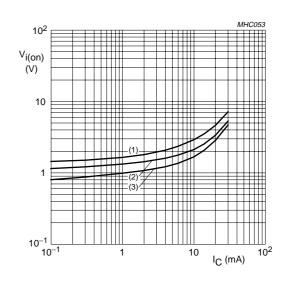
Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



 $V_{CE} = 5 V$.

- (1) $T_{amb} = -40 \, ^{\circ}C$.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = 100 \, ^{\circ}C$.

Fig.5 Input-off voltage as a function of collector current; typical values.



 $V_{CE} = 0.3 V.$

- (1) $T_{amb} = -40 \, ^{\circ}C$.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = 100 \, ^{\circ}C$.

Fig.6 Input-on voltage as a function of collector current; typical values.

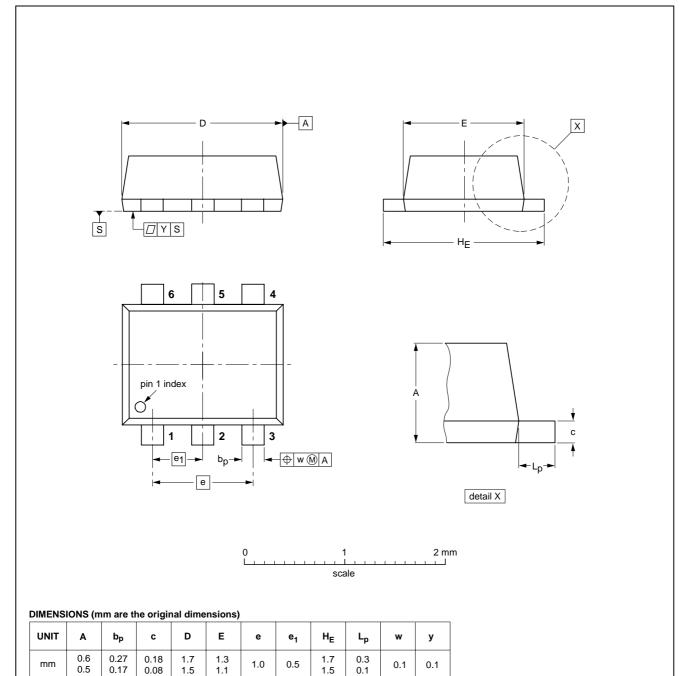
NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



OUTLINE	REFERENCES			EUROPEAN ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT666						-01-01-04 01-08-27	

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